

PA 1279887

REC'D 14 MAR 2005

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February 07, 2005

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APPLICATION NUMBER: 60/538,457

FILING DATE: January 26, 2004

IB 2005 / 45

PRIORITY DOCUMENT

SUBMITTED OR TRANSMITTED IN
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15915 U.S. PTO
13441 U.S. PTO
60/538457
012604

PROVISIONAL APPLICATION COVER SHEET

This is a request for filing a PROVISIONAL APPLICATION under 37 CFR 1.53(c).

Docket Number 248191US2PROV

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TITLE OF THE INVENTION (280 CHARACTERS MAX)

DIAMOND BONDING

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ENCLOSED APPLICATION PARTS

- ☒ Specification Number of Pages: 8 ☐ CD(s), Number
- ☒ Drawing(s) Number of Sheets: 1 ☒ Other (specify): Application Data Sheet, Advance Serial Number Card

METHOD OF PAYMENT

- ☐ Applicant claims small entity status. See 37 CFR 1.27.
- ☒ A check or money order is enclosed to cover the Provisional Filing Fees
- ☐ Credit card payment form is attached to cover the Provisional Filing Fees in the amount of _____
- ☐ The Director is hereby authorized to charge filing fees and credit any overpayment to Deposit Account Number 15-0030

PROVISIONAL \$160.00
FILING FEE
AMOUNT

The invention was made by an agency of the United States Government or under a contract with an agency of the United States Government.

☒ No.

☐ Yes, the name of the U.S. Government agency and the Government contract number are:

Respectfully Submitted,



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PROVISIONAL APPLICATION FILING ONLY

DIAMOND BONDING

BACKGROUND OF THE INVENTION

This invention relates to diamond bonding and, more particularly, to diamond bonding using electron beam heating.

A variety of methods are known for bonding of components, each with its own advantages. Such methods include:

- welding, where a component typically metallic, and filler if used, are melted;
- brazing, where a melted filler chemically reacts with a component surface;
- diffusion bonding, where the components are assembled, generally with a thin layer of a diffusible material placed between them, and then heated under pressure typically to about 0,4 of the absolute melting point of the diffusion bonding layer;
- soldering, where the melted filler wets but does not chemically react with the surface of the component;
- gluing, where a polymeric hardening or reactive process is used.

The bonding processes set out above are listed in a general order of decreasing bond temperature and decreasing bond strength. For any particular application the requirement is to select a process which provides sufficient bond and yet does not degrade the bonded materials significantly due to the bond temperature or other bond characteristics.

Diamond is a difficult material to bond to other materials in a manner that is both strong and reliable. This difficulty is largely due to the very low chemical reactivity of diamond. Further difficulty arises because of its very low thermal expansion compared with other materials, which combined with its high elastic modulus can result in very high thermally induced stresses after a bonding process at raised temperature.

The requirement for bonding diamond elements, such as windows, to frames, typically metal or ceramic, for inclusion into larger assemblies is well established. In many applications this mounting is required to provide mechanical integrity, good thermal contact and in addition a gas tight seal for vacuum, pressure, or fluid containment applications. Generally it is advantageous to minimise the thermal stresses induced by mounting so as to maximise the design strength available for environmental factors. EP 0 761 623A1 describes the use of an active (reactive) braze technique, wherein brazing takes place by heating the entire assembly above the melting point of the high melting temperature ($>450^{\circ}\text{C}$) reactive filler. PCT/IB 00/00172 describes a method of forming a joint between a CVD (chemical vapour deposition) diamond and a metal support structure, where the diamond is first bonded to a ceramic body having thermal expansion characteristics compatible with those of CVD diamond, which in turn is bonded to a dimensionally compliant, intermediate metal element. The metal element is then secured to the metal supporting structure. These intermediate components are designed to reduce the thermal stresses inevitably arising from forming the bond by elevating the temperature of the entire structure. However, in both these cases a limitation is that the final structure is either complex or under significant thermal stress, or both.

SUMMARY OF THE INVENTION

According to the present invention, a method of producing a bonded structure which includes a layer of material capable of forming a diffusion or diffusion-type bond with diamond bonded to a diamond element includes the step of applying electron beam heating to a localised region of contacting surfaces between the diamond and the layer of material, or the layer of material and a surface of a metal element or structure to cause bonding of at least some of the contacting surfaces in that region.

The material of the layer, as mentioned, will be capable of forming a diffusion or diffusion-type bond with the diamond. The material will typically be a carbide forming metal or alloy containing a carbide forming metal. Examples of suitable carbide forming metals are titanium and molybdenum.

Thus, in one form of the invention, a layer of the diffusible material is bonded in a localised region to a surface of a diamond element using electron beam heating.

In another form of the invention, a surface of the diamond is provided with a layer of the diffusible material. In this form of the invention, the coated surface is brought into contact with the surface of a metal element or structure and electron beam heating is applied to create a localised bonding region with the contacting surfaces. This electron beam heating can also be used to create a bond between the layer in contact with the diamond surface, if such bond was not created during coating of that surface. The metal of the element or structure may, for example, be a ferrous metal, a non-ferrous metal or an alloy containing either such metal. Examples of suitable metals and alloys of this nature are copper, aluminium or steel.

The invention has particular application to the bonding of a layer of diamond to a frame or mount. In this form of the invention, the frame or mount will typically be made of the material capable of forming a diffusion

or diffusion-like bond with the diamond. The electron beam heating may be applied to the frame or mount such as to create a localised bond between a surface of the frame or mount and the diamond layer. Alternatively, a thin layer of the material capable of forming a diffusion or diffusion-like bond with the diamond may first be applied to the diamond surface. In this form of the invention, the electron beam heating will create localised bonding between the thin layer and the diamond, where this has not already been formed by the method of applying the layer to the diamond surface, and also between the mount and the thin layer.

The electron beam heating must take place under conditions in which degradation of the diamond is minimised or avoided. Typically the electron beam heating takes place in a vacuum.

The method of the invention has several advantages over known methods of bonding layers to diamond:

1. The process is a clean process in that it is carried out typically in a vacuum chamber.
2. The heat input is very rapid and highly localised and thereby minimising the total energy input and damage to the diamond.
3. The bond is narrow.
4. No filler material is required.
5. The heat affected region is small.
6. The likelihood of thermal effects, such as diamond element distortion, is reduced.
7. The process is well suited to precision bonding.

Typical conditions for producing suitable electron beam heating are currents in the range 0.01A – 10A and voltages in the range 1 kV – 100 kV.

It is preferred that the conditions of electron beam heating are such that there is a substantial absence of any melting of the material of the layer, in particular away from the local area being immediately heated by the electron beam and at the diamond surface.

Where used, the intermediate layer of material capable of forming a diffusion or diffusion-like bond with the diamond may be applied to a surface of the diamond by a variety of known techniques. Amongst these are evaporation, where the diffusion bond between this layer and the diamond will not generally be formed at this stage, and sputtering, where the diffusion bond between this layer and the diamond may generally be at least partly formed.

The method of the invention is applicable to a variety of diamond elements. The diamond of these elements may be that produced by chemical vapour deposition (CVD diamond) and may be polycrystalline or single crystal in nature. The diamond may also be natural single crystal diamond or single crystal diamond synthesised by high temperature/high pressure techniques.

BRIEF DESCRIPTION OF THE DRAWINGS

- Figure 1** illustrates a sectional side view of a first embodiment of the invention, and
- Figure 2** illustrates a sectional side view of a second embodiment of the invention.

DESCRIPTION OF EMBODIMENTS

Embodiments of the invention will now be described with reference to the accompanying drawings. In these embodiments, a diamond layer or window is bonded to a supporting cylinder.

Referring first to Figure 1, a diamond window or layer 10 is mounted in a cylinder 12. The cylinder 12 consists of two interlocking sections 14, 16. The lower section 14 has a recess 18 in which the diamond layer 10 is located. The section 16 has a matching end profile 20 creating an overlapping join.

In order to create a bond between the section 14 and the diamond layer 10, the assembly is placed in a chamber of an electron beam welding machine and rotated about the axis 22. The electron beam is applied in the direction of arrow 24 which is perpendicular to the axis of rotation 22. The beam is directed at the outside surface 26 of the section 14. The heating effect of the electron beam results in bonding between the diamond layer 10 and the section 14 in the narrow and localised region indicated by 30.

In a specific example of the invention, a polycrystalline CVD diamond layer or window 10 was prepared with lapped flat faces and laser cut edges. The CVD diamond layer 10 was mounted in a titanium cylinder 12 as indicated in Figure 1. An electron beam was directed at the assembly, as described above, resulting in the formation of a thin layer of titanium carbide at the interface between the diamond layer 10 and the section 14 in the region 30. It was only necessary to supply sufficient heat to the assembly for the titanium in contact with the diamond to react with the diamond. The titanium of the tube was locally melted at the external surface, but not melted at the surface in contact with the diamond. The entire bonding process took a few tens of seconds.

On removal of the bonded assembly from the vacuum chamber, the join was shown to be leak tight to better than 10^{-8} Pa.l/s with negligible

distortion. An added advantage of the method described above is that the localised heating and absence of fusion meant there was no overrun of the window by bond material that required subsequent cleaning.

In another specific example of the invention, a diamond window in a titanium cylinder was produced, except that prior to placing the diamond layer 10 in the assembly, a thin layer of titanium was sputter coated on the peripheral surface 34 of the diamond layer 10.

A second embodiment of the invention is illustrated by Figure 2. Referring to this figure, a diamond layer or window 40 is mounted in a cylinder 42. The cylinder 42 comprises upper and lower sections 44, 46. The sections 44, 46 have end sections 48, 50 which are recessed. The sections, when joined, create a butt joint at 52. The butt jointed sections define a recess which accommodates a peripheral edge 54 of the diamond layer 40.

In order to bond the sections 44, 46 to the diamond, the cylinder is rotated about the axis 56. Electron beam heating is directed at the butt joint 50 in direction of arrow 58 perpendicular to the axis of rotation. The electron beam conditions are chosen to achieve melting of the outer surface of the tube thus forming a butt weld joint between the sections 44 and 46 and a temperature at the edge surface 60 of the diamond window such as to create a diffusion bond between the diamond and the sections 44, 46. The surface 60 may be titanium coated in which case it is the titanium coat which will form a diffusion bond with the diamond.

In the embodiments described above, the electron beam conditions may be chosen such as to obtain melting of the cylinder sections to a point where such melting takes place at the diamond edge surface.

Where electron beam heating is being used for two separate functions, for example creating the diffusion bond with the diamond element or the bond between the layer on the diamond and the mount (or both of these) and in addition is used to form the joint between two elements of the mount, then

these two functions may be completed in a single electron beam processing step, or in two immediately sequential steps, or in two separate sequential steps, depending on the application.

